

N-Channel JFET

General Purpose Amplifier

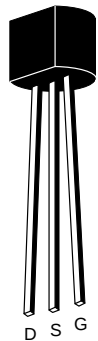


J201 – J204 / SST201 – SST204

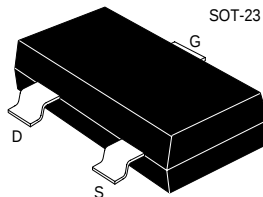
FEATURES

- High Input Impedance
- Low I_{GSS}

PIN CONFIGURATION



TO-92



SOT-23

5010

PRODUCT MARKING (SOT-23)

SST201	A01
SST202	A02
SST203	A03
SST204	A04

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$ unless otherwise specified)

Gate-Source or Gate-Drain Voltage	-40V
Gate Current	50mA
Storage Temperature Range	-55°C to $+150^\circ\text{C}$
Operating Temperature Range	-55°C to $+135^\circ\text{C}$
Lead Temperature (Soldering, 10sec)	$+300^\circ\text{C}$
Power Dissipation	360mW
Derate above 25°C	3.3mW/ $^\circ\text{C}$

NOTE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ORDERING INFORMATION

Part	Package	Temperature Range
J201-204	Plastic TO-92	-55°C to $+135^\circ\text{C}$
SST201-204	Plastic SOT-23	-55°C to $+135^\circ\text{C}$

For Sorted Chips in Carriers see 2N4338 series.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

SYMBOL	PARAMETER	201			202			203			204			UNITS	TEST CONDITIONS
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		
I_{GSS}	Gate Reverse Current (Note 1)			-100			-100			-100			-100	pA	$V_{DS} = 0, V_{GS} = -20V$
$V_{GS(off)}$	Gate-Source Cutoff Voltage	-0.3		-1.5	-0.8		-4.0	-2.0		-10.0	-0.3		-2.0	V	$V_{DS} = 20V, I_D = 10nA$
BV_{GSS}	Gate-Source Breakdown Voltage	-40			-40			-40			-25				$V_{DS} = 0, I_G = -1\mu A$
I_{DSS}	Saturation Drain Current (Note 2)	0.2		1.0	0.9		4.5	4.0		20	0.2	1.2	3.0	mA	$V_{DS} = 20V, V_{GS} = 0$
I_G	Gate Current (Note 1)		-10			-10			-10			-10		pA	$V_{DG} = 20V, I_D = I_{DSS(min)}$
g_{fs}	Common-Source Forward Transconductance (Note 2)	500			1,000			1,500			500	1,500		μS	$V_{DS} = 20V, V_{GS} = 0$
g_{os}	Common-Source Output Conductance		1			3.5			10			2.5			$f = 1kHz$
C_{iss}	Common-Source Input Capacitance		4			4			4			4		pF	$f = 1MHz$ (Note 3)
C_{rss}	Common-Source Reverse Transfer Capacitance		1			1			1			1			
$\bar{e}_n$	Equivalent Short-Circuit Input Noise Voltage		5			5			5			10		$\frac{nV}{\sqrt{Hz}}$	$V_{DS} = 10V, V_{GS} = 0, f = 1kHz$ (Note 3)

- NOTES:**
1. Approximately doubles for every 10°C increase in T_A .
 2. Pulse test duration = 2ms.
 3. For design reference only, not 100% tested.

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Datasheets for electronics components.